

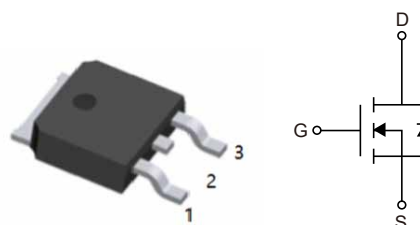
1.Features

- $V_{DS(V)}=100V$
- $I_D=90A(V_{GS}=10V)$
- $R_{DS(ON)}<6.8m\Omega(V_{GS}=10V)$
- Excellent gate charge x $R_{DS(ON)}$ product (FOM)
- Very low on-resistance $R_{DS(ON)}$
- 175 °C operating temperature
- Ideal for high-frequency switching and synchronous rectification

2.Pinning information

Pin	Symbol	Description
1	G	GATE
2	D	DRAIN
3	S	SOURCE

TO-252(DPAK)
top view



3.Absolute Maximum Ratings $T_J=25^{\circ}C$

Parameter	Symbol	Conditions	Value	Units
Continuous drain current	I_D	$T_C=25^{\circ}C^{2)}$	90	A
		$T_C=100^{\circ}C$	72	A
Pulsed drain current ²⁾	$I_{D,pulse}$	$T_C=25^{\circ}C$	360	A
Avalanche current, single pulse	E_{AS}	$I_D=90A, R_{GS}=25\Omega$	130	mJ
Gate source voltage	V_{GS}		± 20	V
Power dissipation	P_{tot}	$T_C=25^{\circ}C$	150	W
Storage temperature	T_J, T_{STG}		-55 to 175	$^{\circ}C$
IEC cimatic category; DIN IEC 68-1			55/175/56	



4. Electrical Characteristic (T_J=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Thermal resistance, junction -case	R _{thJC}				1	K/W
Thermal resistance, junction - ambient	R _{thJA}	minimal footprint			62	K/W
		6 cm ² cooling area ³⁾			40	K/W
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =1mA	100			V
Gate threshold voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =90μA	2	2.7	3.5	V
Zero gate voltage drain current	I _{DSS}	V _{DS} =100V, V _{GS} =0V, T _J =25°C		0.1	1	μA
		V _{DS} =100V, V _{GS} =0V, T _J =125°C		10	100	μA
Gate-source leakage current	I _{GSS}	V _{GS} =20V, V _{DS} =0V		1	100	nA
Drain-source on-state resistance	R _{DS(ON)}	V _{GS} =10V, I _D =90A		5.7	6.8	mΩ
		V _{GS} =6V, I _D =45A		7.1	12.3	mΩ
Gate resistance	R _G			1.6		Ω
Transconductance	g _{FS}	V _{DS} >2 I _D R _{DS(ON)max} , I _D =90A	54	107		S
Input capacitance	C _{iss}	V _{GS} =0V, V _{DS} =50V, f=1MHz		3690	4910	pF
Output capacitance	C _{oss}			646		pF
Reverse transfer capacitance	C _{rss}			25		pF
Turn-on delay time	t _{D(on)}	V _{DD} =50V, V _{GS} =10V I _D =80A, R _{G,ext} =3.6Ω		19		ns
Rise time	t _r			37		ns
Turn-off delay time	t _{D(off)}			37		ns
Fall time	t _f			9		ns
Gate to source charge	Q _{gs}	V _{DD} =15V, I _D =30A V _{GS} =0 to 4.5V		18		nC
Gate to drain charge	Q _{gd}			10		nC
Switching charge	Q _{SW}			17		nC
Gate charge total	Q _g			51	68	nC
Gate plateau voltage	V _{plateau}			4.9		V



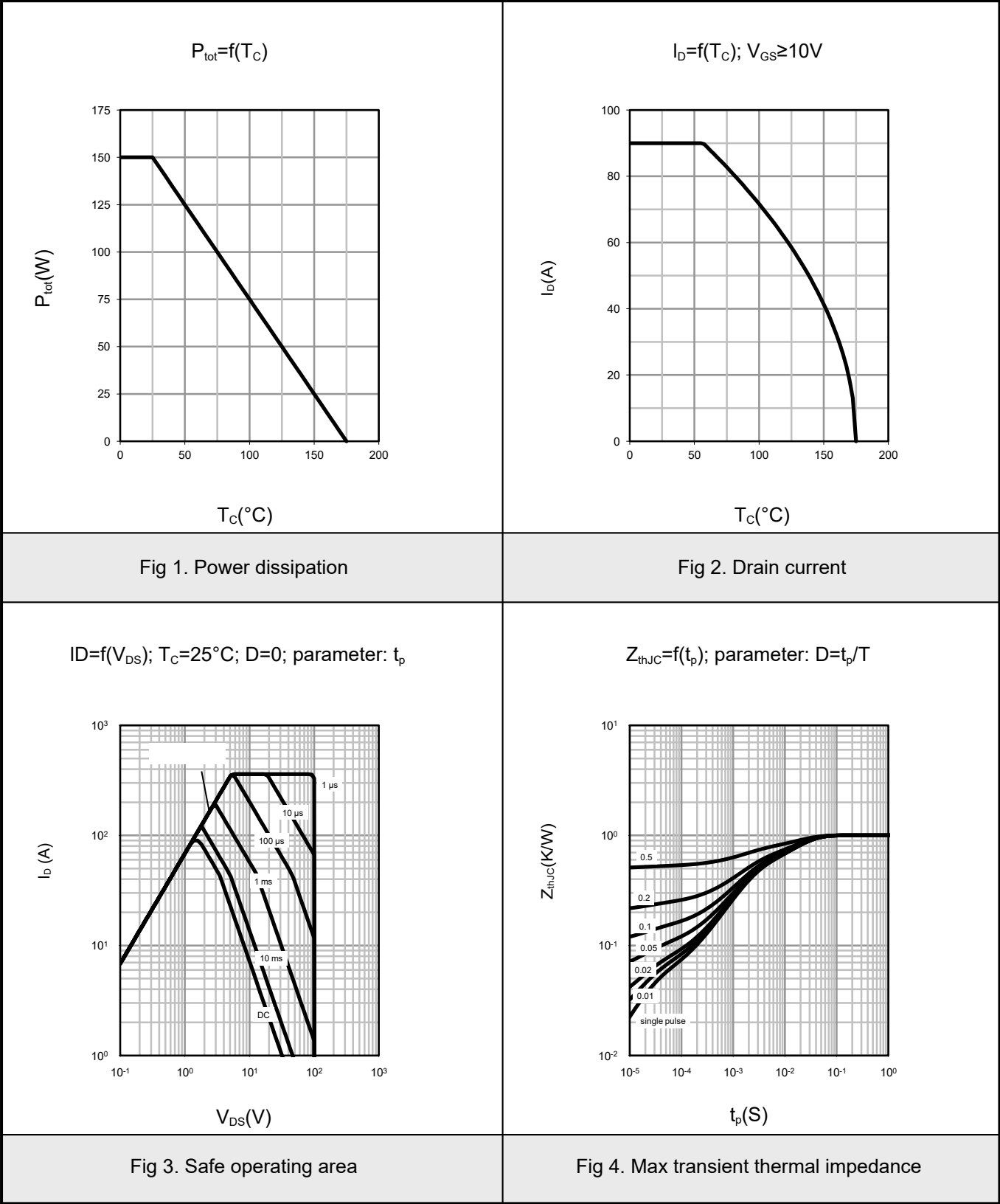
Output charge	Q_{oss}	$V_{DD}=50V, V_{GS}=0V$		68	91	nC
Diode continuous forward current	I_S	$T_C=25^{\circ}C$			90	A
Diode pulse current	$I_{S,pulse}$				360	A
Diode forward voltage	V_{SD}	$V_{GS}=0V, I_F=90A, T_J=25^{\circ}C$		1	1.2	V
Reverse recovery time	t_{rr}	$V_R=15V, I_F=80A, di_F/dt=100A/\mu s$		73		ns
Reverse recovery charge	Q_{rr}			139		nC

Notes:

6) See figure 16 for gate charge parameter definition.

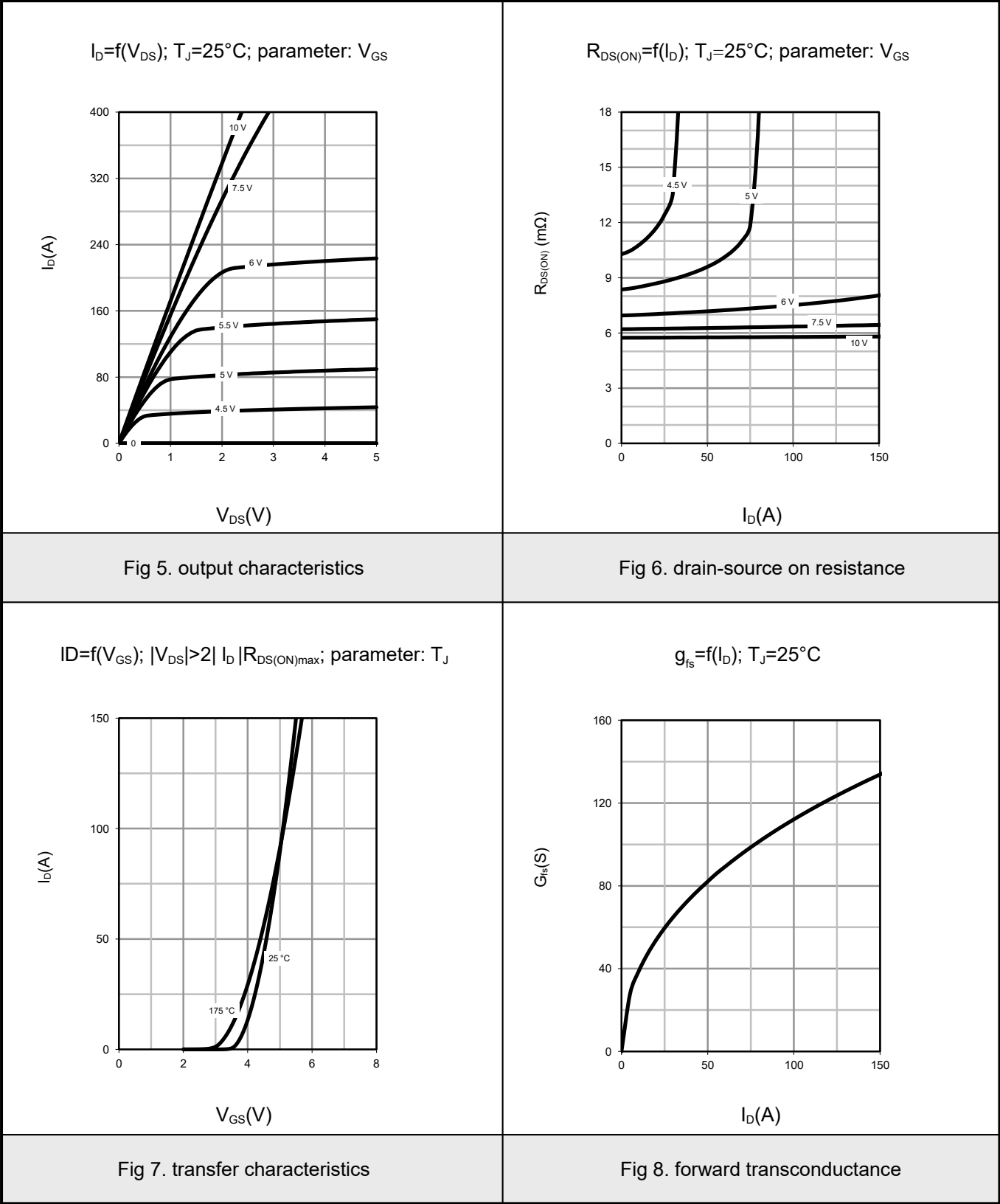


5.1Typical characteristic



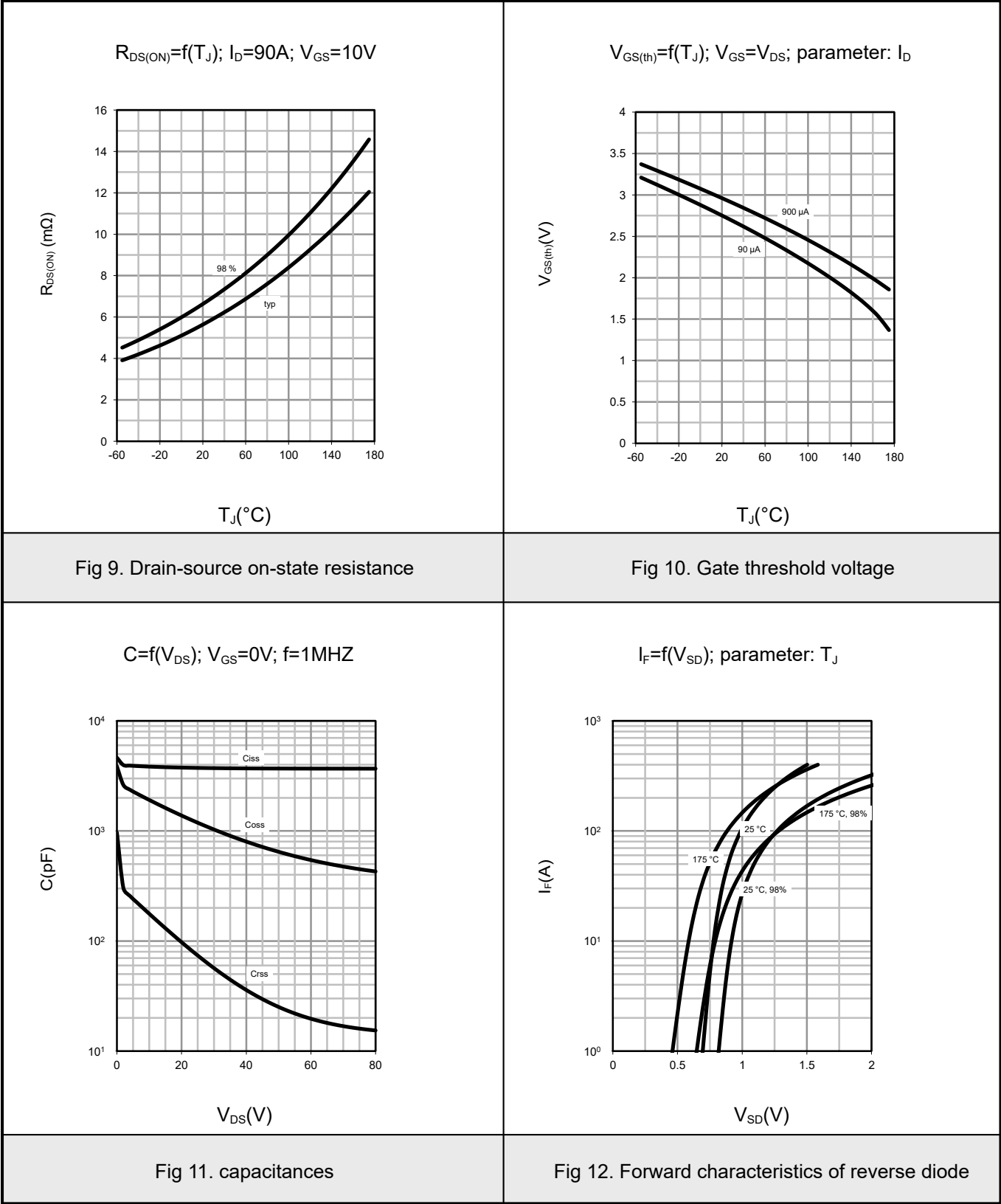


5.2Typical characteristic



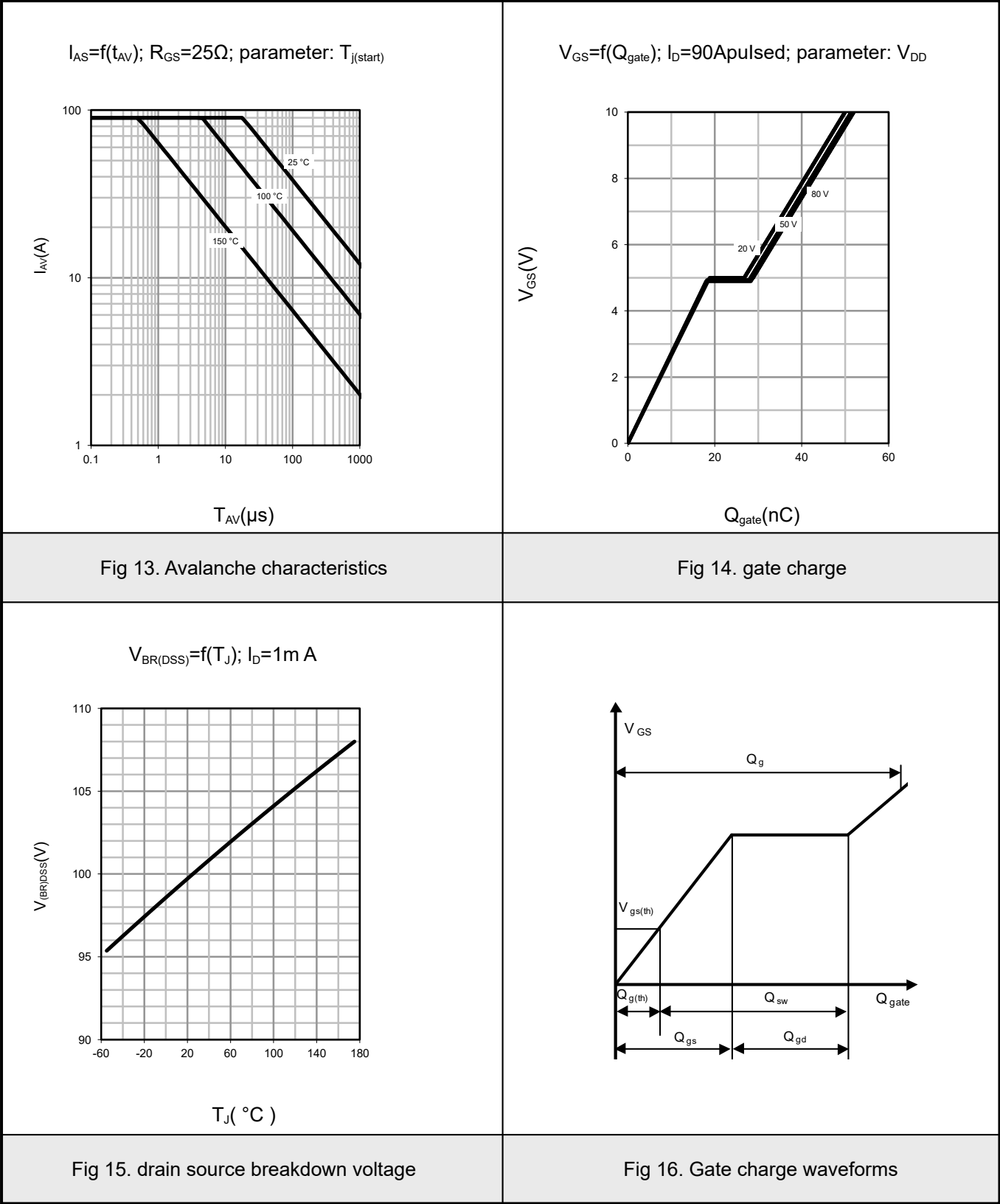


5.3Typical characteristic



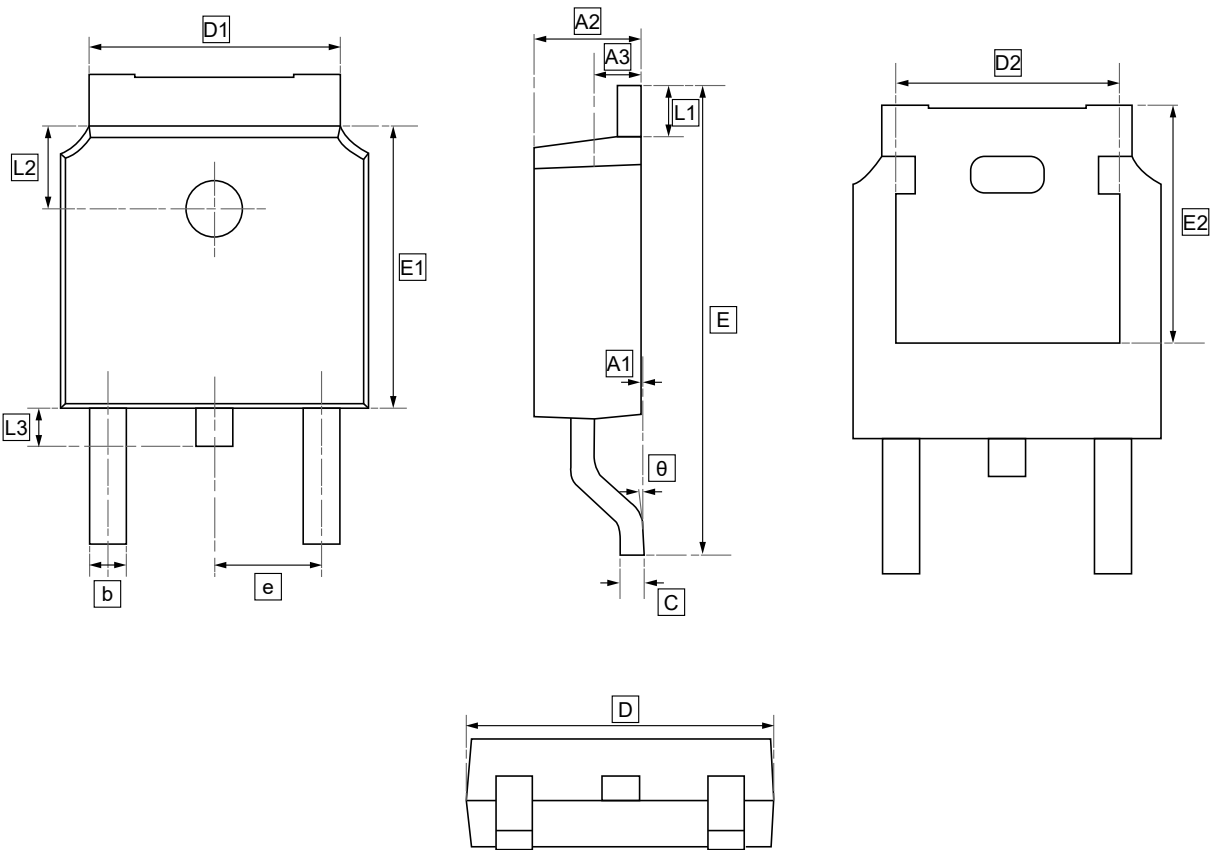


5.4Typical characteristic





6.TO-252 Package Outline Dimensions

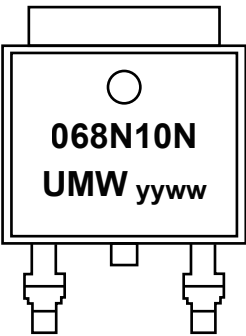


DIMENSIONS (mm are the original dimensions)

Symbol	A1	A2	A3	b	c	D	D1	D2	E	E1	E2	e	L1	L2	L3	θ
Min	0.00	2.18	0.90	0.65	0.46	6.35	4.95	4.32	9.40	5.97	5.21	2.286 BSC	0.89	1.70	0.60	0.00
Max	0.13	2.39	1.10	0.85	0.61	6.73	5.46	4.90	10.41	6.22	5.38		1.27	1.90	1.00	8.00



7.Ordering information



yy: Year Code
ww: Week Code

Order Code	Package	Base QTY	Delivery Mode
UMW IPD068N10N3G	TO-252	2500	Tape and reel



8.Disclaimer

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